Schottky Barrier Diode

#### DB2G32600L1

# **Panasonic**

### DB2G32600L1

#### For rectification

#### ■ Features

- Low forward voltage VF
- Forward current (Average) IF(AV) ≦ 1.0 A rectification is possible
- RoHS compliant (EU RoHS / MSL:Level 1 compliant)

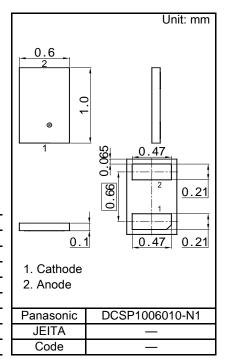
■ Marking Symbol: A4

#### ■ Packaging

Embossed type (Thermo-compression sealing): 1 000 pcs / reel (standard)

#### ■ Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Reverse Voltage *1	VR	-	30	V
Maximum Peak Reverse Voltage *1	VRM	-	30	V
Average Forward Current *2,3	IF(AV)	-	1.0	Α
Average Forward Current *2,4	IF(AV)	-	1.0	Α
Non-repetitive Peak Surge Forward Current *1,5	IFSM	-	15	Α
Operating Junction Temperature *6	Tj	-	150	ŷ
Ambient Temperature	Та	-40	+150	ŷ
Storage Temperature	Tstg	-55	+150	Ŝ



Note) \*1: Ta = Tj = 25°C

\*2: Squre wave :  $\sigma$  = 0.5

\*3: Ta ≦ 102°C, when device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).

- \*4: Tsp ≦ 139°C
- \*5: Squre wave : Tp = 5 ms
- \*6: Power derating is necessary so that Tj < 150°C.

(Waveform definition)	IF <b>↑</b> ← Tp
Duty Cycle : $\sigma = \frac{Tp}{T}$	Time
	Time

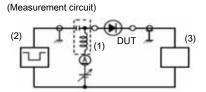
#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward Voltage	VF	IF = 1.0 A	-	0.35	0.44	V
Reverse Current	IR	VR = 30 V	-	200	900	μA
Terminal Capacitance	Ct	VR = 10 V, f = 1 MHz	-	32	-	pF
Reverse Recovery Time *1	trr	IF = IR = 100 mA, Irr = 10 mA	-	10	-	ns

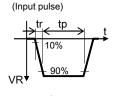
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - $2. \quad \text{This product is sensitive to electric shock (static electricity, etc.)}.$

Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

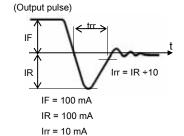
3. \*1: Measurement circuit, input pulse, output pulse for Reverse recovery time



- (1) Bias Insertion Unit (N-50BU)
- (2) Pulse Generator (PG-10N), RS =  $50 \Omega$
- (3) Wave Form Analyzer (SAS-8130), Ri = 50  $\Omega$



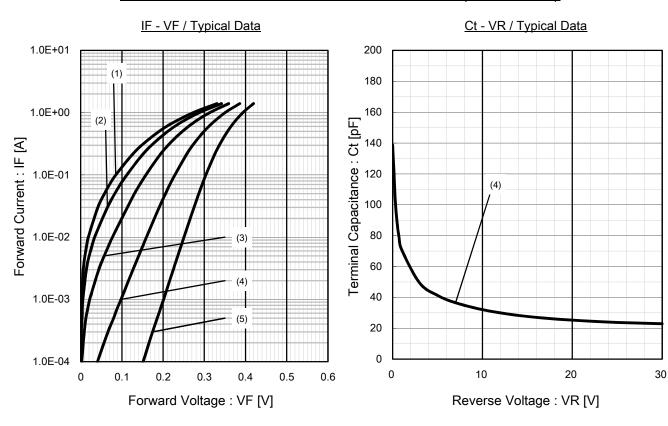
 $tp = 2 \mu s$ tr = 0.35 ns $\sigma = 0.05$ 



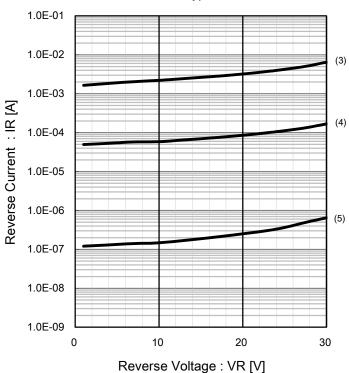
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## Electrical Characteristics Technical Data (Reference)



IR - VR / Typical Data



(Graph legends)

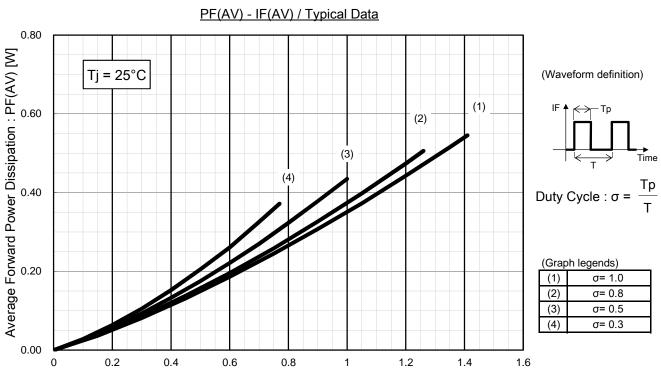
(Olap	in legend	13)		
(1)	Ta =	150	°C	
(2)	Ta =	125	°C	
(3)	Ta =	85	°C	
(4)	Ta =	25	°C	
(5)	Ta =	-40	°C	

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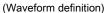
## **Panasonic**

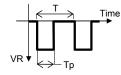
### Electrical Characteristics Technical Data (Reference)



Average Forward Current: IF(AV) [A]

## PR(AV) - VR / Typical Data 0.0080 Average Reverse Power Dissipation: PR(AV) [W] Tj = 25°C 0.0060 (1) 0.0040 (2) (3) 0.0020 (4) 0.0000 0 10 30





Duty Cycle :  $\sigma = \frac{Tp}{T}$ 

(Graph legends)

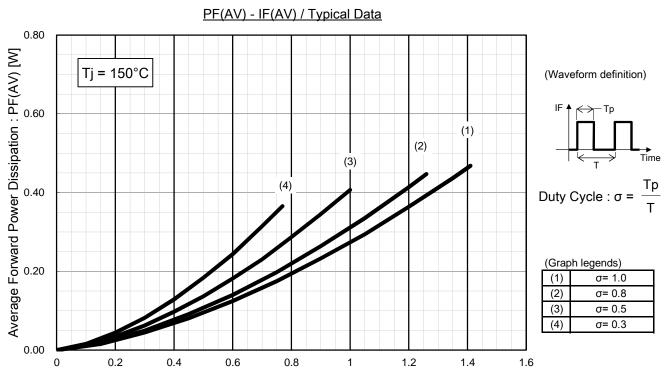
(Ο.αρ	ii logoliao)
(1)	σ= 1.0
(2)	σ= 0.7
(3)	σ= 0.5
(4)	σ= 0.2
	(2)

Reverse Voltage: VR [V]

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### Electrical Characteristics Technical Data (Reference)



Average Forward Current : IF(AV) [A]

#### PR(AV) - VR / Typical Data 0.30 Average Reverse Power Dissipation: PR(AV) [W] Tj = 85°C (Waveform definition) 0.20 (1) Duty Cycle : $\sigma = \frac{Tp}{T}$ (2) 0.10 (3) (Graph legends) σ= 1.0 σ= 0.7 (4) σ= 0.5 (3) (4) $\sigma$ = 0.2 0.00 30 10

Reverse Voltage: VR [V]

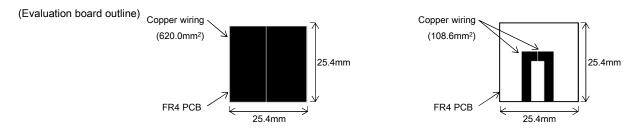
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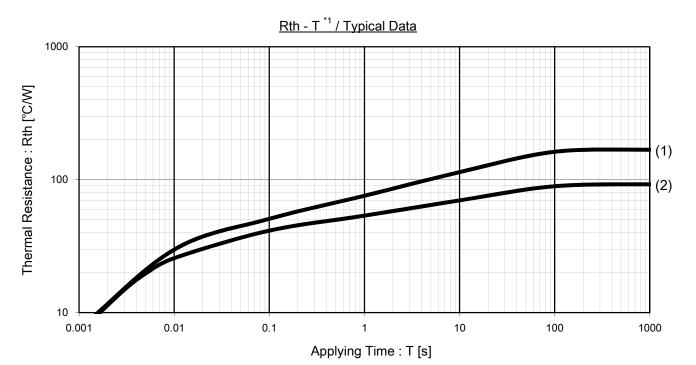
#### ■ Thermal Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Thermal Resistance, Junction to Solder Point	$R_{th(j-sp)}$	Ta = 25°C, in free air	-	20	1	°C/W
Thermal Resistance, Junction to Ambient *1	R <sub>th(j-a)</sub>	Ta = 25°C, in free air	-	92	-	°C/W
Thermal Resistance, Junction to Ambient *2	R <sub>th(j-a)</sub>	Ta = 25°C, in free air	-	170	-	°C/W

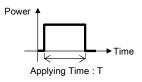
- Note) \*1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).
  - \*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (108.6mm² area, 36µm thick).



### Thermal Characteristics Technical Data (Reference)



Note) \*1: Single pulse measurement (Waveform definition)

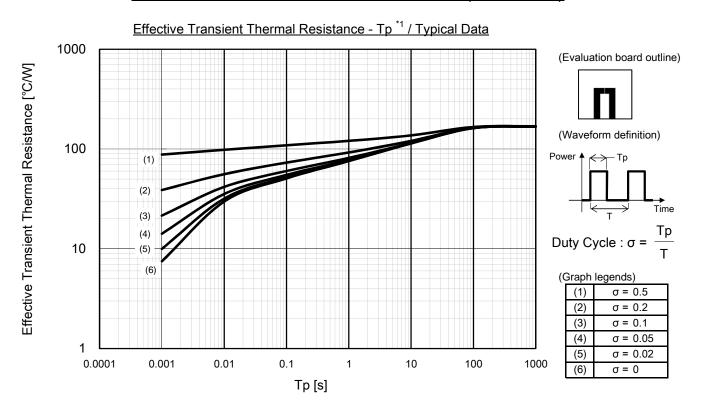


(Graph legends)

ľ	(1)	Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick),
	(1)	copper wiring (108.6mm <sup>2</sup> area, 36µm thick).
	(2)	Device mounted on a FR4 PCB (25.4mm, 1mm thick),
	(2)	copper wiring (620.0mm <sup>2</sup> area, 36µm thick).

#### DB2G32600L1

## Thermal Characteristics Technical Data (Reference)

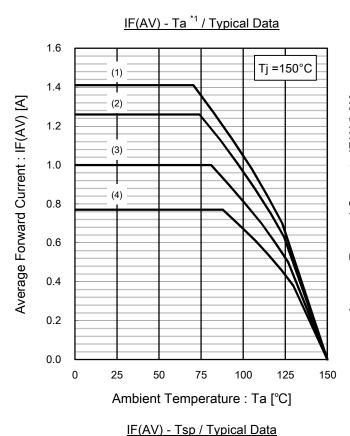


#### Effective Transient Thermal Resistance - Tp \*2 / Typical Data 1000 (Evaluation board outline) Effective Transient Thermal Resistance [°C/W] (Waveform definition) 100 (1) (2) Duty Cycle : $\sigma = \frac{Tp}{T}$ (3) 10 (5) (Graph legends) $\sigma = 0.5$ $\sigma = 0.2$ (2) $\sigma = 0.1$ (3) $\sigma = 0.05$ $\sigma = 0.02$ 0.0001 0.001 0.01 0.1 1 10 100 1000 $\sigma = 0$ Tp[s]

Note) \*1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (108.6mm² area, 36µm thick). \*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).

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### Power Derating Technical Data (Reference)



1.6 Tj =150°C (1) 1.4 Average Forward Current: IF(AV) [A] (2) 1.2 (3) 1.0 (4) 8.0 0.6 0.4 0.2 0.0 25 50 75 100 150 125 Ambient Temperature : Ta [°C]

IF(AV) - Ta \*2 / Typical Data

1.6

1.4

(1)

Tj =150°C

Tj =150°C

(2)

1.2

(3)

(4)

0.8

(4)

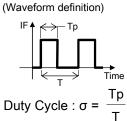
0.6

0.4

0.2

0.0

(Graph legends)	vaveto
(1) $\sigma = 1.0$	IF∱
(2) $\sigma = 0.8$	
(3) $\sigma = 0.5$	
(4) $\sigma = 0.3$	



#### Note)

\*1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (108.6mm² area, 36µm thick).

(Evaluation board outline)



\*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).

(Evaluation board outline)



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25

50

75

Solder Point Temperature: Tsp [°C]

100

125

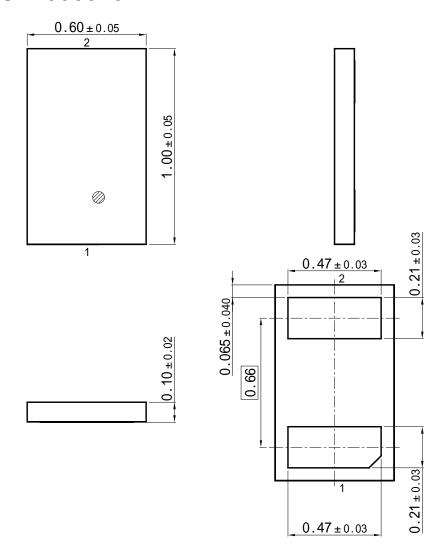
150

Schottky Barrier Diode

### DB2G32600L1

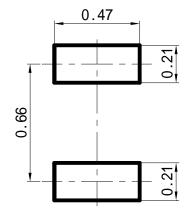
## DCSP1006010-N1

Unit: mm



■ Land Pattern (Reference)

Unit: mm



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